NSN 5961-01-114-4273

Transistor - Page 1 of 1

View Online at https://aerobasegroup.com/nsn/5961-01-114-4273

Inclosure Material:

Ceramic

Overall Height:

Between 0.149 inches and 0.187 inches

Overall Diameter:

Between 0.165 inches and 0.185 inches

Function For Which Designed:

Microwave

Mounting Facility Quantity:

2

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 collector to base voltage/static/emitter open and 18.0 breakdown voltage, collector to emitter, sustained and 3.5 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

0.50 milliamperes zero-gate-voltage source current preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0

